Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:	
Ceramic and metal	
Overall Length:	
0.970 inches	
Overall Diameter:	
1.930 inches	
Mounting Method:	
Press fit	
Semiconductor Materia	al:
Silicon	
Voltage Rating In Volts	Per Characteristic:
2600.0 repetitive peak r	everse voltage and 2600.0 repetitive peak off-state voltage
Current Rating Per Cha	aracteristic:
600.00 amperes forward	current, total rms horsepower metric and 380.00 amperes forward current, total rms universal
Terminal Type And Qu	antity:
2 case and 2 insulated w	vire lead
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	